Structure, elastic properties and strength of am orphous and nanocom posite carbon

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A bstract

We study theoretically the equilibrium structure, as well as the response under external load, of characteristic carbon-based materials. The materials considered include diamond, am orphous carbon (a-C), am orphous diamond and nanocomposite am orphous carbon (na-C). A universal bulk-modulus versus density curve is obeyed by all structures we consider. We calculate the dependence of elastic constants on the density. The strength of a-C was found to increase in roughly a linear manner, with increasing concentration of four-fold atoms, with the maximum stress of the strongest a-C sample being about half that of diamond. The response of na-C to external load is essentially identical to the response of the embedding a-C matrix.

Keywords:

A m orphous carbon, nanocom posite carbon, m echanical properties, fracture. PACS: $81.07\,B\,c$, 62.25+g, $81.05\,G\,c$.

1. Introduction

Am orphous carbon (a-C) is a well-established carbon-based material, with distinct mechanical properties such as hardness and thermal stability. These properties render a-C to be an ideal material for coating applications. Recently, nanocomposite carbon (na-C) has been synthesized in both hydrogenated and pure forms [1]. It is considered as a material with similar, and perhaps better properties than those of a-C. Na-C consists of nanometer-scale regions of crystalline material embedded into an a-C matrix. This material has mechanical properties between those of a-C and diamond [2], that could in principle be ne-tuned by adjusting either the size of the nanocrystalline region or the density of the am orphous matrix. Such tailoring of ma-

terial properties to m atch those desired in the applications could be invaluable.

The properties of a-C and na-C can be categorized into two broad classes: The rst class includes m acroscopic, mean—eld properties, such as the density, that are implicatly only related to individual chemical bonds. A tom istic properties, on the other hand, such as the strength, arise directly from the individual chemical bonds between C atoms of dierent electronic structure. The macroscopic properties are usually related to the minimum or the harmonic regime of the cohesive energy versus volume curve, and can, therefore, be easily calculated using any reasonable description for the bonds. On the other hand, even a rough estimate of atom istic properties requires employing some level of quantum theory.

A quantum -m echanical treatm ent is able to accurately describe the chem icalbond, but can only be used to study few hundreds of atoms for very short time scales. On the other hand, a classical empirical potential method can handle three orders of magnitude more atoms for realistic time scales, at the price of a limited accuracy in the description

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of the chem istry of carbon. This interplay between classical and quantum -m echanical simulations has been used to verify or predict several experim ental ndings for na-C: D iam ond nanocrystallites were found to be stable, having negative form ation energy, when the am orphous matrix is dense [3]. The average intrinsic stress of the material is zero [4]. A Lthough the bulk modulus of na-C is higher than that ofa-C, the twom aterials have identical ideals trength due to identical fracture mechanisms [2]. In this work, we rst establish the validity of our simulations by ensuring that different approximations yield identical qualitative and similar quantitative results. We then study in more detail the elastic properties of these materials, including the dependence of elastic moduli as a function of their density. Finally, we comm ent on their behavior under strain well beyond the elastic regime, and discuss brie y their fracture.

2. Com putationalM ethod

The quantum -m echanical calculations are based on two di erent tight-binding ham iltonians. The so-called NRL-TB was developed by Papaconstantopoulos, Mehl and co-workers at the Naval Research Laboratory [5]. The param etrization of the ham iltonian for C is based on similar assum ptions to the previously published param etrization for Si; see Ref. [6] for a review . The environm ent-dependent tight-binding (EDTB) modelofW ang, Ho and co-workers [7] goes beyond the traditional two-center approximation and allows the TB param eters to change according to the bonding environment. In this respect, it is a considerable im provem ent over the previous two-center model of Xu et al. [8]. Both NRL-TB and EDTB schemes have been used successfully to simulate a-C systems [9,2]. The tightbinding molecular-dynamics simulations simulations are carried out in the canonical (N, V, T) ensemble, T being controlled via a stochastic tem perature control algorithm. The supercells used in the tight-binding simulations contain 512 C atom seach.

The empirical potential simulations are based on the continuous-space M onte Carlo method. We employ the many-body potential of Terso [10], which provides a very good description of structure and energetics for a wide range of carbon-based materials [11,12]. This method allows for great statistical accuracy, as it is possible to have samples at full thermodynamic equilibrium. Moreover, through the use of relatively large supercells, it o ers the possibility to explore a larger portion of the congurational space of the problem. The supercells used in the Monte Carlo simulations contain 4096 Catom seach.

Na-C is modeled by a periodic repetition of cubic supercells that consist of a spherical crystalline region surrounded by a-C. To construct such supercells, we rst consider a cubic supercell of diam ond, and choose the radius of the spherical crystalline phase. Keeping the atoms in-

side this sphere frozen to their diam ond lattice positions, we run the system at a very high tem perature (12000-15000 K) so that a liquid is created, and then quench it down to 50 K, at constant volume. A fler that, the system is fully equilibrated by relaxing both the system volume and the coordinates of all atoms. In the M onte C arbo simulations, we perform an additional intermediate relaxation at room temperature to ensure that the sample is fully relaxed.

By adjusting the volume or, equivalently, the pressure of the liquid phase, we can create samples having low-or high-density a-C. It has been shown that properties of a-C can be described in terms of a single parameter, z [9]. This is the average coordination number, or number of neighbors, for each atom in the sample. More precisely, z it is the integral of the nearest-neighbor peak of the paircorrelation function. By convention, individual atoms in a-C are thought of having an electronic structure in oneto-one correspondence to their coordination number: four-, three-and two-fold atoms are usually labeled in the literature as sp³, sp² and sp¹, respectively. A lthough for most atoms such a relationship between coordination number and hybridization holds to a good approximation, other atom ic electronic structures may be present as well. We create samples with average coordination between 3.1 and 3.9, having concentrations of four-fold coordinated atom s between 10 and 90%. Samples with z & 3.8 are considered as tetrahedralam orphous Carbon (ta-C). We also consider the fully tetrahedral W ooten-W iner-W eaire (W W W) structure [13], as a model for \am orphous diam ond". The radius of the nanocrystalline region is of the order of 2 nm (1 nm for the quantum -m echanical simulations), while it occupies about 30-40% of the total volume, in accordance to experim ental observations [14].

3. Equilibrium structural properties

Structural properties of diam ond, \am orphous diam ond and a-C are sum marized in Table 1. For diam ond, we calculate the density () and the bulk modulus (B) using the two tight-binding schemes and the Terso potential. All methods yield results in good agreement to experiment. The a-C samples we considered consist mostly of four—and three—fold atoms, while two—fold atoms appear in low—density samples. Using the EDTB model, we had found that the density of a-C depends linearly on z, via 3:3+1:7z [9]. We not that the linear relationship found using EDTB is also valid within NRL-TB, at least for the denser samples.

Insight into the atom istic structure of a-C can be gained by looking at the sizes and distributions of rings of atom s in the m aterial. Rings of atom s are de ned in term s of the shortest-path criterion of Franzblau [15]. The number of atom s that participate in a ring is the ring size, and can have only speci c values for a bulk crystalline m aterial: in diam ond, for example, the smallest ring size is six. On

Table 1 Structural properties of diamond (D), \amorphous diamond" (W W W) and four characteristic a-C samples (A-D). All samples are simulated using NRL-TB, except D (E), D (T) and D (e) that contain results obtained from the EDTB, Terso potential and experiment, respectively. N4, N3 and N2 is the percentage of four-, three- and two-fold atom s, respectively. B is the bulk modulus (in GPa), the calculated density (in gr/cm 3), and fit is the density (in gr/cm 3) according to the t of vs.z from Ref. [9].

	Z	N 4	N ₃	N ₂	В		fit
D	4.0	100	0	0	480	3 . 7	
D (E)	4.0	100	0	0	428	3.5	
D (T)	4.0	100	0	0	422	3.5	
D (e)	4.0	100	0	0	443	3.5	
w w w	4.0	100	0	0	434	3.4	3.5
A	3.8	78	22	0	387	3.1	3.2
В	3.7	67	32	1	361	2.9	3.0
С	3.5	47	52	1	325	2.5	2.7
D	3.2	18	77	5	211	1.6	2.1

the contrary, three-m ember rigs are common in a- \mathbb{C} . As the formation of rings is related to atom istic binding, a quantum -m echanical treatment is necessary in order to get reliable ring statistics.

Results for the relative ring numbers and concentrations, found using the NRL-TB for three characteristic samples, are shown in Fig. 1. Similar results have been obtained with EDTB [9]. For the low-density sample, we not significant numbers for three-and four-member rings, while the most probable ring length is six. For ta-C, the most probable ring length is ve, while there are still some three-and four-member rings. Finally, for the \amorphous diamond" sample, most rings are six-membered, with few ve-and seven-member ones. A lthough, by construction, only four-fold atoms exist in this sample, its random topology allows for rings that would not be present in the crystalline material.

The bottom panel of Fig. 1 shows the composition of rings as a function of their size, for the ta-C sample. Most atoms (over 90%) of the smallest rings are four-fold. The concentration of four-fold atoms decreases with increasing ring size; for large rings, with more that eight members, most atom sare three-fold. This behavior can be attributed to the long-range correlations found for -bonded atom s; such bonds are more likely to occur between three-than between four-fold atom s. On the other hand, such double bonds are more di cult to bend in order to form triangles or quadrangles; this is why most atom s that participate in small rings are four-fold.85% of the three-member rings and 75% of the four-member rings consist of four-fold atom s only, while there are no rings of sizes 8 and above having only four-fold atom s. The ring statistics presented here are in excellent agreem ent to experim ents and state-

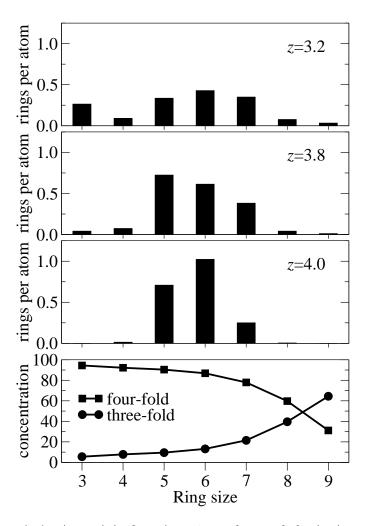


Fig. 1. Ring statistics for various a-C samples, as calculated using the NRL-TB. The upper three panels show the number of rings divided by the total number of atoms in the sample, as a function of the number of atoms participating in each ring, for three cases: low-density a-C (z= 3.18), ta-C (z= 3.78) and \amorphous diam ond (z= 4.00). Lowest panel shows the concentration of rings in four-fold and three-fold atoms for the ta-C sample.

of the art ab initio simulations [16,17].

A typical sample of na-C, generated in the NRL-TB scheme is shown in Fig. 2. The volume fraction of the nanocrystalline region is 31%. The surrounding am orphous material is ta-C (z=3.8 and = 3.0 gr/cm 3). A sample created using EDTB under identical conditions has the same crystal volume fraction and a-C coordination, and only slightly higher density of the am orphous phase, 3.1 gr/cm 3 . In all cases, the surrounding a-C matrix obeys the same density vs. coordination relationship as pure a-C samples generated using the same recipe. The a-C atoms are covalently bonded to the crystal, resulting thus in thin interface regions.

As a \mbox{rst} estimate of the hardness of nanocom posite nd/a-C structures, we calculated their bulk modulus, B . In Fig. 3, we plot B as a function of the total density of the

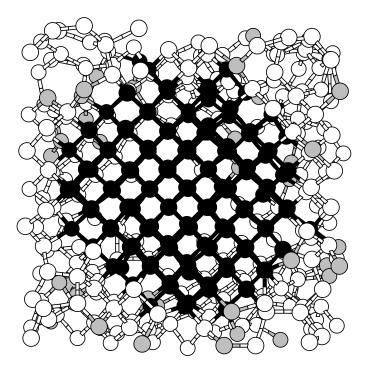


Fig. 2. C ross-section of a ball-and-stick representation for a typical model structure of nanocomposite am orphous C arbon created using EDTB: a spherical nanocrystal with a diameter of $1.24\,\mathrm{nm}$ is embedded into amorphous-C with an average coordination of $3.8.\,\mathrm{A}\,\mathrm{tom}$ s belonging to the crystal are represented by black spheres; four-and three-fold atoms of the amorphous matrix are represented by white and gray spheres, respectively.

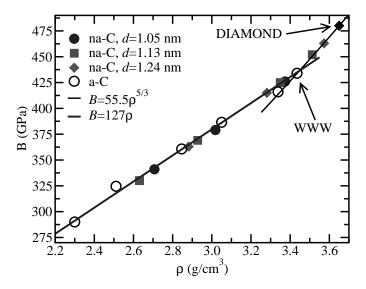


Fig. 3.Bulk m odulus as a function of density, calculated within NR-L-TB, for na-C with di erent radii of the crystalline region. Calculations for a-C of various densities, bulk diam ond and \am orphous diam ond mare also shown.

sam ples, . The bulk modulus of na-C is enhanced compared to that of pure a-C [2]. Replacement of some amorphous material by crystalline increases noticeably the bulk modulus, rendering it for some samples to be higher even than that of the \amorphous diamond", and close to that of diamond [2].

Interestingly, all samples, including pure a-C, na-C, W W W, and even diam ond, seem to follow the same universal curve in Fig.3. Such universalities have been observed in the past: He and Thorpe [18] showed that B (z z0) $^{1.5}$, where z0 is universal; Liu et al. [19] showed that B d $^{3.5}$, where d is the average distance between atom s. Recently, M athioudakis et al. [9] showed that the two approaches are equivalent, and that for a-C, B (d const.) $^{3.5}$. The last relationship would in ply that B ($^{1-3}$ const.) $^{3.5}$. Indeed, this function ts very well the data of Fig.3.

The universal dependence of B on can be understood by considering the m icroscopic response of the m aterial to the external pressure. We can think of two regimes: in low-density m aterials, the pressure is undertaken by appropriately adjusting the volume of the void regions of the material. Such voids exist in every low-density material and are a result of induced dipole (van der Waals) interactions. On the other hand, for dense materials, strong covalent bonds have to be deformed, resulting in higher bulk moduli. In this case, the resistance of the electrons to compression follows from their quantum nature and the Pauli principle.

In the rst case, the scaling of B with respect to can be found by considering a model solid bonded exclusively through van der W aals interactions. U sing the Lennard-Jones potential we can nd that B 20]. On the other hand, for high densities, we can get the correct scaling by using the free-electron approximation: in this case, B

 $^{5=3}$ [20]. This picture is demonstrated in Fig. 3:B for . 3.3 gr/cm 3 , while B $^{5=3}$ for & 3.3 gr/cm 3 . These relationships hold with surprisingly good accuracy.

Being such a fundam ental average property, the B vs. curve should be reproduced well by both our tight-binding m odels and the empirical potential, as the latter is known to reproduce correctly the elastic response of the material. On the other hand, the density dependence of elastic constants associated with changes in shape, like the Young's m odulus, can bedi erent. Although the response of materials to volum e changes can be addressed at alm ost any level of theory, understanding the response to shape changes requires a model that takes into account the directionality of the chemical bonds. Fortunately, as the calculation of elastic constants require only smalldeform ations from them inim um energy structure, the empirical potential approach should su cefortheir calculation. A sthe Monte Carlo simulations o ergreater statistical accuracy and refer to more realistic sizes of the crystalline regions, we prefer to employ this method for the calculation of elastic constants.

To calculate the elastic constants, we apply the appro-

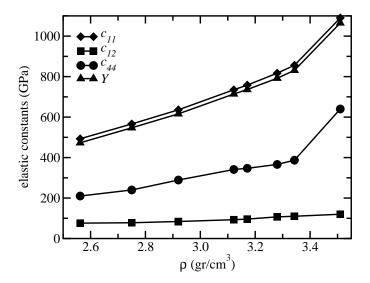


Fig. 4. E lastic constants of na-C, calculated using the Terso potential, as a function of the total density. The average diam eter of the crystalline region is 1.7 nm, and the surrounding a-C m atrix has z=3.8. The rightm ost point for each data set, for a density =3.51 gr/cm 3 , corresponds to diam ond and is taken from Ref. [11].

priate deform ation to the system and compute its total energy as a function of the imposed strain. The curvature of this function at its minimum yields the desired modulus. The number of independent elastic constants depends on the sym m etry of the material: For a material with cubic sym m etry, there are three independent elastic constants, while for an isotropic material, such as a-C or na-C, there are only two [21]. In Fig. 4 we plot c_{11} , c_{12} , c_{44} and the Young's modulus Y as a function of density for na-C and diam ond. A llelastic constants increase with increasing density, similar to the previously described behavior of the bulk m odulus as a function of density. For an isotropic material, $2c_{44} = c_{11}$ c_{12} . This relationship holds within 4% or less, for all data points presented in Fig. 4, dem on strating that na-C is a highly isotropic material. The modulic11 and c44 are both associated with changes in shape, and this is why their values for na-C are much lower than the corresponding values for diam ond, where strong directional bonds are bent. On the other hand, c12 describes simultaneous elongation along two axes without shearing, and the value of this modulus for diamond follows the trend observed for na-C.

4. IdealStrength and fracture

The response of covalently-bonded m aterials, such as a-C and na-C, under strain can be categorized into three broad regim es: For sm all strains, the response of the m aterial is elastic, and H ooke's law stands: the stress is proportional to the applied strain. For example, if tensile strain is applied to an isotropic m aterial, the stress will equal the strain times the Young's modulus. The second regime cor-

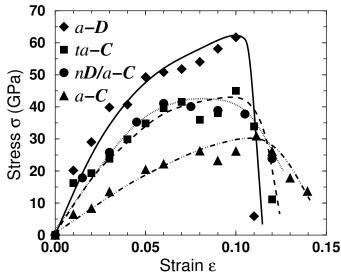


Fig. 5. Stress vs. strain curves for W W W model of \amoophous diamond" (diamonds), ta-C (squares), low-density a-C (triangles) and na-C (circles). The latter consists crystalline regions of 1.2 nm surrounded by ta-C .D ata shown are obtained by the NRL-TB method for tensile load in the (111) direction of the crystal.

responds to strain beyond the elastic lim it, and is usually associated with plastic deformation of the material. The stress experienced by thematerial increases with increasing strain until a maximum stress (strength) is reached. The third regime is associated with strain beyond that giving the maximum stress. For brittle materials like diamond, the material breaks when the maximum stress is reached, and further increase of the strain results therefore in zero stress. Ductile materials, on the other hand, can be deformed beyond the strain corresponding to the maximum of the stress.

To study the strength of a-C and na-C, we apply tensile load on the [111] easy slip plane of the crystalline region. Strain is simply the ratio of the volume change divided by the initial volume of the sample; stress is the negative derivative of the energy with respect to volume. We consider three a-C sam ples: a typical a-C sam ple with average coordination z=3.47, a ta-C sample with z=3.8 and an \amorphous diam ond sam ple. A s graphite (z= 3) is known to be much softer than diam ond (z=4), it is reasonable to expect that the strength increases with increasing z, as was the case for the elastic constants discussed in Section 3. This is observed in Fig. 5. The maximum stresses are roughly 60, 40 and 30 GPa for z = 4.00, 3.78 and 3.50, respectively, so that the strength of a-C is roughly proportional to its concentration of four-fold atom s. Interestingly, the stress versus strain curve for the low-density a-C sample seems to suggest a ductile behavior.W e get sim ilar results when applying shear strain. As a-C is highly isotropic, the energy required to deform the material is a function of the change in its volum e and does not depend much on how this change is applied.

The strength of diam and does not tinto the simple picture of the strength being proportional to the concentration of four-fold atoms. If that was the case, then the strength of the isotropic W W W sam ple under tensile load would be higher than the strength of diam ond under tensile load perpendicular to its easy slip plane, (111). After all, in the W W W model the number of bonds per unit area for a given direction has to be higher than the number of bonds per unit area on the [111] plane of diam ond. This justi es the nam e \easy slip plane" for the diam ond (111). One could naively expect that the strength of the W W W sample, consisting of four-fold atoms only, could perhaps be higher than that of diam ond, due to the lack of such easy slip planes. On the contrary, the calculation reveals that the strength of diam ond for tensile load along its easy slip direction, (111), is about twice that of the isotropic W W. Apparently, the lack of easy slip planes in W W W is com pensated by its somehow distorted bonds and the lack of order beyond the rst-nearest-neighbor distance.

We applied the same methodology to a na-C sample where crystalline regions having radii of about 12 nm are embedded in ta-C with a volume fraction of about 30%. The stress-strain curve for this sample follows exactly that of the embedding ta-C. The crystalline phase remains una ected by the external load, which is almost completely taken by the surrounding am orphousm atrix. Therefore, the response of na-C to external load beyond the elastic regim e is identical to the response of the embedding matrix. As atom s in the am orphousm atrix form bonds that are always weaker than the bonds in the crystal, the system prefers to stretch or bend these bonds and keep the strong diam ond bonds untouched. By performing an atom-by-atom analysis of the deform ation, we can probe the four-fold atom s of the am orphous atom s as the ones m ore extensively deform ed when the material experiences large load [2].

5. Conclusions

We exam ined theoretically the structure, elastic and inelastic response to load of several carbon-based materials, including diamond, am orphous carbon (a-C) \amorphous diamond" (WWW) and nanocomposite amorphous carbon (na-C). These materials are formed by covalently bonded four-fold and three-fold atoms and are characterized by their average coordination number (z). In a-C, three-, four- and ve-member rings are formed, their number increasing with decreasing z.M ost of such small rings contain four-fold atoms, while larger rings contain also three-fold atoms. The bulk modulus of all these carbon-based materials seems to follow a universal functional dependence of the density. All elastic constants were also found to increase with increasing density.

The strength of a-C was found to increase in roughly a linear manner, with increasing concentration of four-fold atom s. High-density sample exhibited a brittle behavior, analogous to that of diam ond. The strongest a-C sample we considered was the \am orphous diam ond "W W W sample; this has a maximum stress about half that of diam ond. The response of na-C to external load is essentially identical to the response of the embedding a-C matrix.

6. A cknow ledgm ent

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